

10 WATT POWER AMPLIFIER MODULE, 800 - 2000 MHz

Features

- P1dB Output Power: 10 Watts
- Gain: 43 dB
- Output IP3: +56 dBm
- Single Positive Supply: +12V
- Thermally Compensated and Protected
- TTL DC Power Enable
- Unconditionally Stable
- Heat Sink/Fan Accessories Available

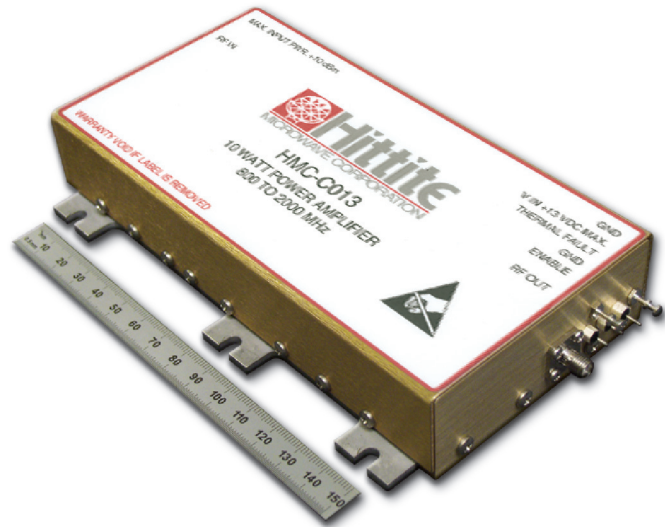
Typical Applications

The HMC-C013 is ideal for:

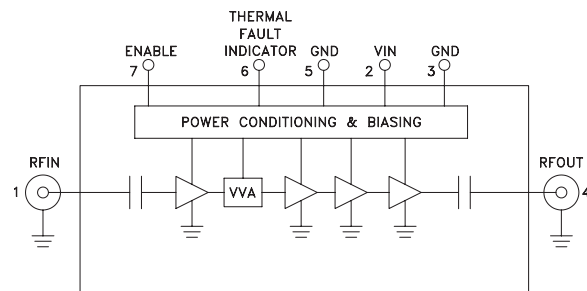
- Cellular/PCS/3G Infrastructure
- Automated Test Equipment (ATE)
- Laboratory Use

General Description

The HMC-C013 is a 10 Watt Power Amplifier Module suitable for Cellular/3G repeaters, wireless data, laboratory use and ATE applications. This extremely robust PA module is DC blocked, internally regulated and over voltage protected. Thermal protection/fault circuitry automatically turns off DC power if base temperature exceeds +75 °C and restores power at < +55 °C.



Functional Diagram

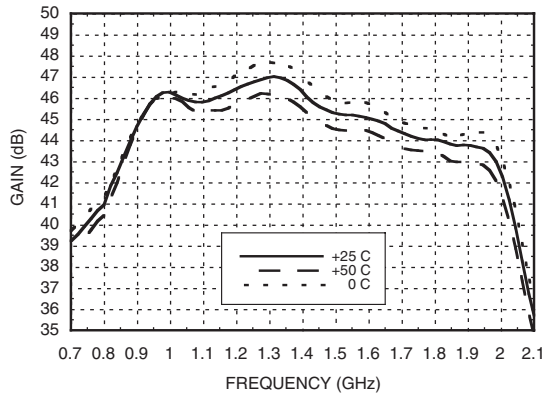


Electrical Specifications, $T_A = +25^\circ \text{C}$, $V_{IN} = +12\text{V}$

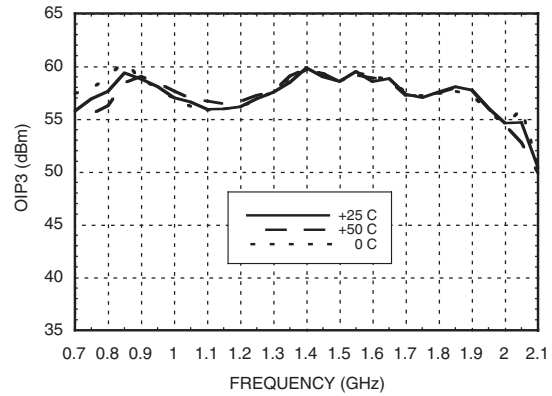
Parameter	Min.	Typ.	Max.	Units
Frequency Range	0.8 - 2.0			GHz
Gain	39	43		dB
Input Return Loss	9.5	12		dB
Output Return Loss	7.5	14		dB
Output Power for 1 dB Compression (P1dB)	9	10		W
Saturated Output Power (Psat)		42		dBm
Output Third Order Intercept (IP3) (Two-tone Input Power = -28 dBm each tone)		56		dBm
Channel Output Power for -60 dBc ACPR (CDMA-2000, 1.98 MHz offset)		38		dBm
Channel Output Power for -50 dBc ACPR (CDMA-2000, 885 kHz offset)		35		dBm
Second Harmonic at Output P1dB		-20		dBc
Third Harmonic at Output P1dB		-30		dBc
Spurious at Output P1dB		-65		dBc
Supply Current		6.5	7.0	A

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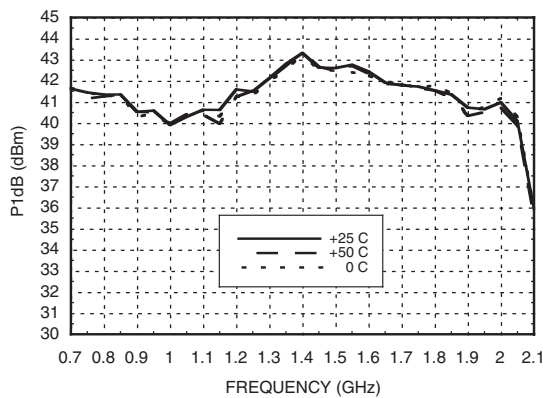
Gain vs. Temperature



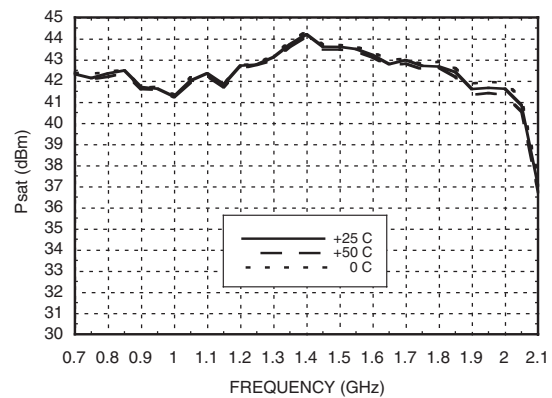
Output IP3 vs. Temperature



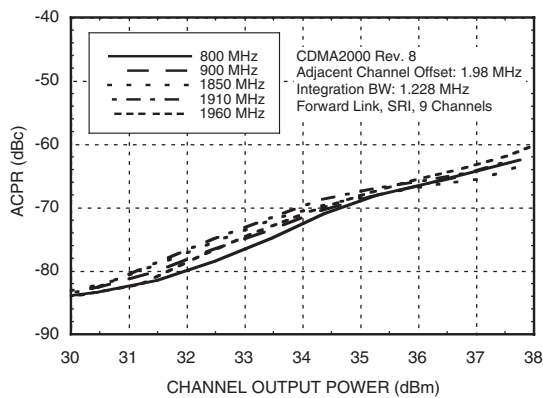
P1dB vs. Temperature



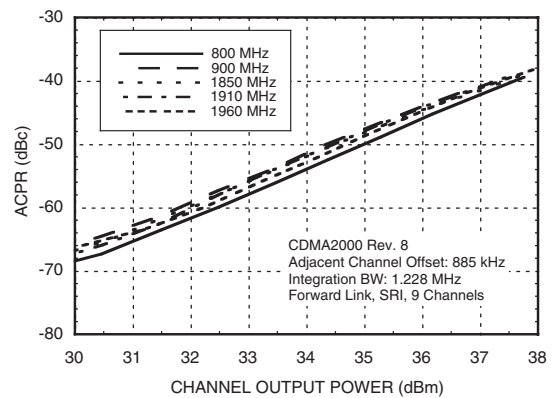
Psat vs. Temperature



ACPR, CDMA-2000, 1.98 MHz Offset

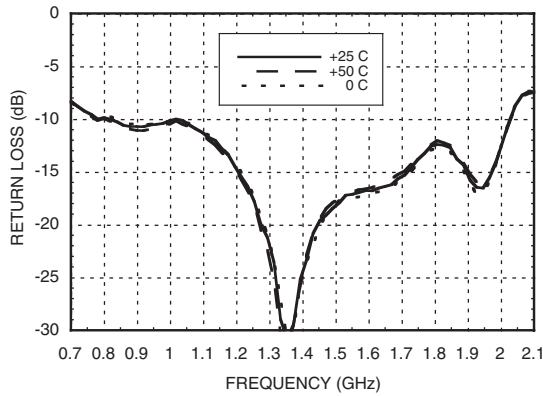


ACPR, CDMA-2000, 885 kHz Offset

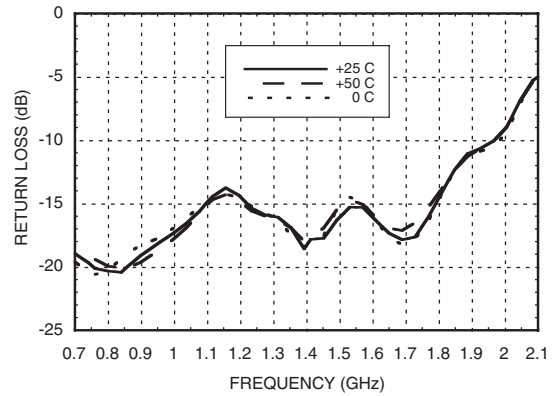


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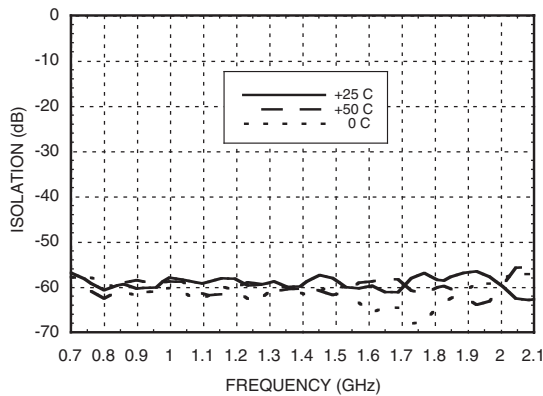
Input Return Loss vs. Temperature



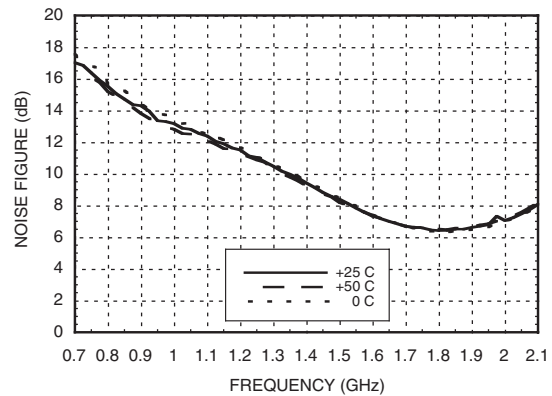
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



Noise Figure vs. Temperature



Absolute Maximum Ratings

Supply Voltage (VIN)	+13 Vdc
RF Input Power (RFIN)	+10 dBm
Storage Temperature	-40 to +85 °C
Operating Temperature	0 to +50 °C
Thermal Fault Indicator Max Pdiss (derate 1.8 mW/°C above 50 °C)	180 mW
Enable	-0.5 to +6.0 Vdc

**Thermal Fault Indicator
Characteristics**

Parameter	Min.	Typ.	Max.	Units
I _{OUT} (V _{OUT} > 2V)		350		mA
R _{ON} (I _{OUT} = 50 mA)			7.5	Ohms
R _{OFF} (V _{OUT} = 30 V)		1		MOhm



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Enable Input Characteristics

Parameter	Min.	Typ.	Max.	Units
V _{IH}	3.5			V
V _{IL}			1.6	V
I _{IL} @ VIN = 0V		-0.5		mA
I _{IH} @ 5V		< ± 50		µA

Recommended Biasing Procedure

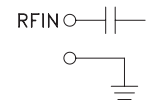
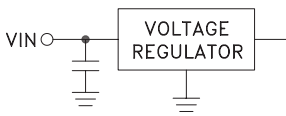

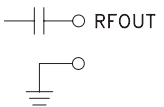

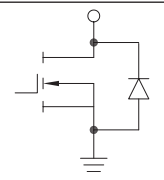
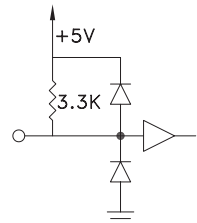
TURN-ON

1. Connect RF input and output
2. Apply Supply Voltage VIN (+12 Vdc)
3. Set Enable low
4. Apply RF input signal

TURN-OFF

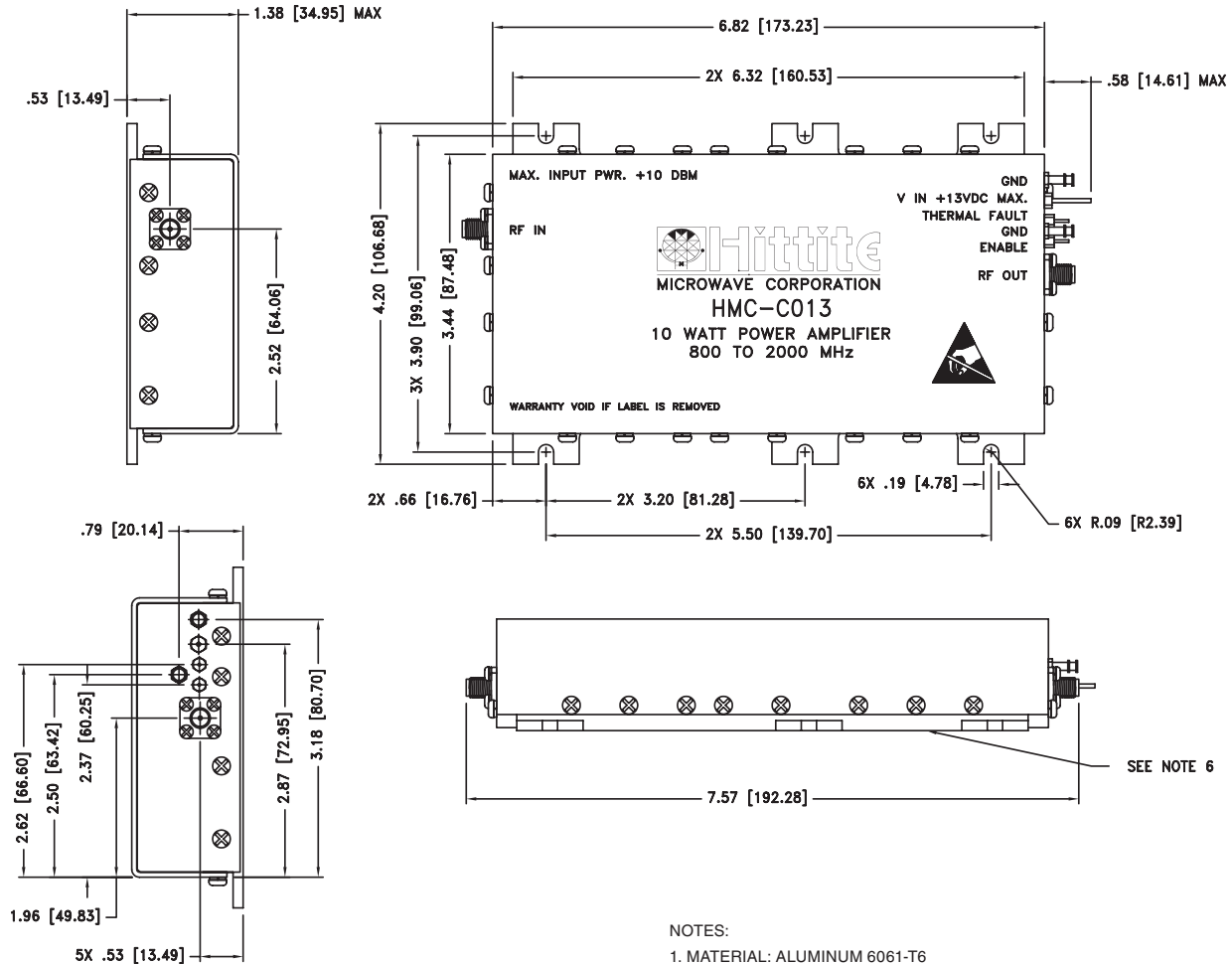
1. Remove RF input signal
2. Remove Supply Voltage VIN

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN & RF Ground	RF input connector, SMA female. This pin is AC coupled and matched to 50 Ohms from 800 - 2000 MHz.	
2	VIN	Power supply voltage for the amplifier.	
3	GND	Power supply ground.	
4	RFOUT & RF Ground	RF output connector, SMA female. This pin is AC coupled and matched to 50 Ohms from 800 - 2000 MHz.	
5	GND	Ground for thermal fault indicator and enable circuit.	
6	Thermal Fault Indicator	Open drain output. High impedance for base plate temperatures less than 55 °C. Low impedance for base plate temperatures exceeding 75 °C.	
7	Enable	TTL compatible supply voltage (VIN) shutdown. If enable feature is not required, short this pin to DC ground. TTL "High" Disable TTL "Low" Enable	

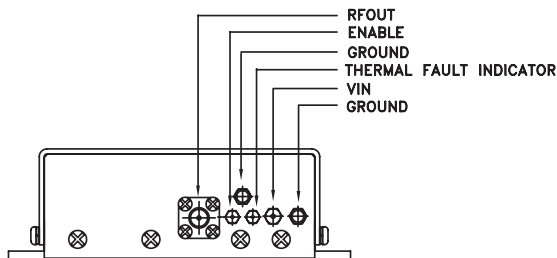
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Outline Drawing



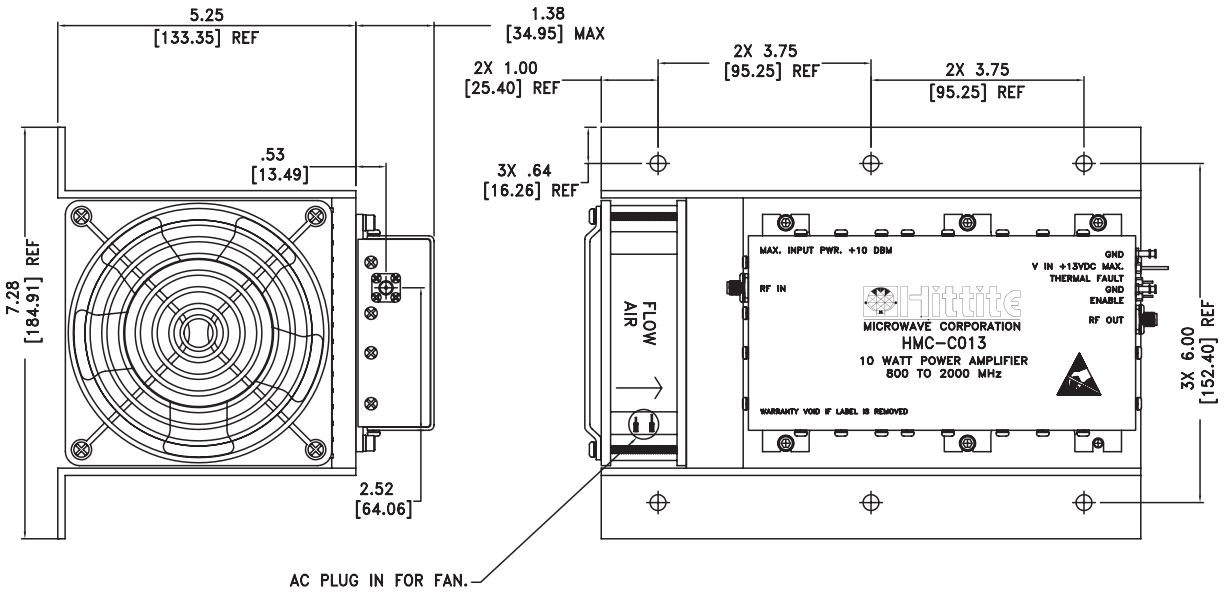
NOTES:

1. MATERIAL: ALUMINUM 6061-T6
2. FINISH
 - a. COVER & END PLATES, CHEMICAL FILM PER MIL-C-5541, CLASS 3
 - b. BASE, TIN
3. RF CONNECTORS, SMA STYLE
4. DIMENSIONS ARE INCHES (MM)
5. TOLERANCES $.X \pm .1$ (2.54mm)
 $.XX \pm .02$ (0.50mm)
6. DRAWING TO CHANGE AS REQUIRED.
7. BASE MUST BE GROUNDED AND MOUNTED TO HEAT SINK CAPABLE OF DISSIPATING 100W (65 °C)



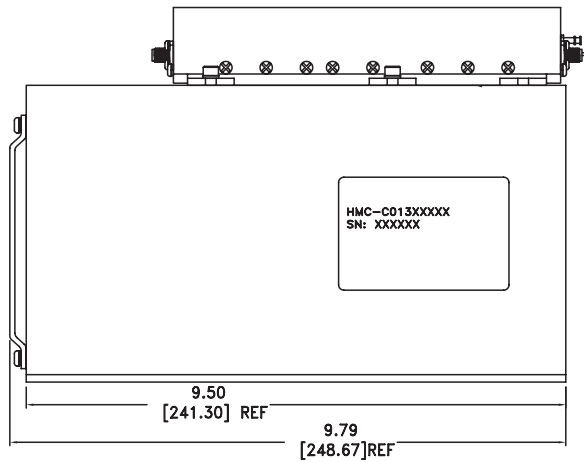
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HMC-C013 Heatsink/Fan Outline Drawing



NOTES:

1. MATERIAL: ALUMINUM 6061-T6
2. FINISH: COVER & END PLATES, CHEMICAL FILM PER MIL-C-5541, CLASS 3
3. RF CONNECTORS, SMA STYLE
4. DIMENSIONS ARE INCHES (MM)
5. TOLERANCES .X±.1 (2.54mm)
.XX±.02 (0.50mm)



HMC-C008 Ordering Information

Part Number	Description
HMC-C013	10 Watt Power Amplifier Module, 800 - 2000 MHz
HMC-C013HV115	10 Watt Power Amplifier Module with heat sink, 115 Vac fan and power cord.
HMC-C013HV230	10 Watt Power Amplifier Module with heat sink, 230 Vac fan and power cord.

